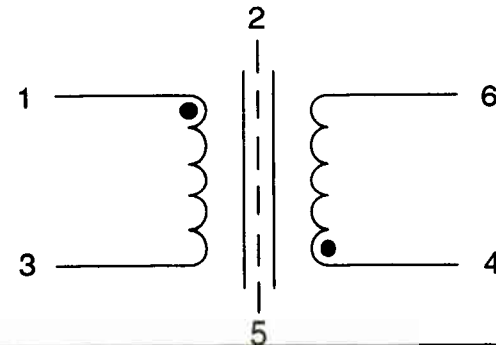
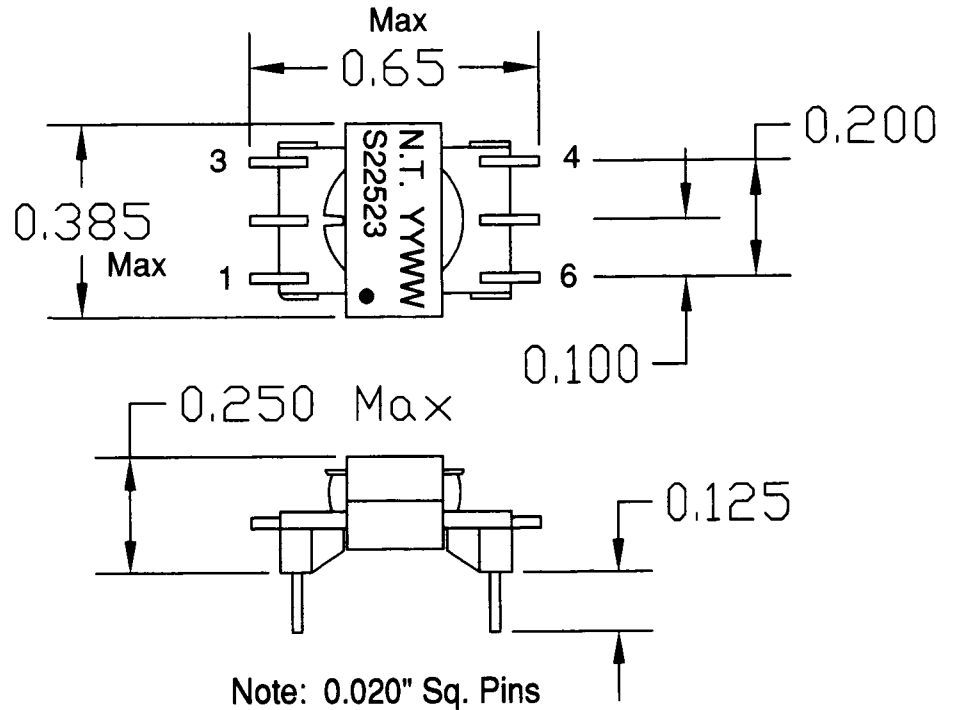


**SPECIFICATIONS:**

1. INDUCTANCE: @ 10 kHz, 0.1 Vrms,  
1 - 3 > 225 uHy
2. DCR: mOHMS Nom  
1 - 3 = 0.1  
4 - 6 = 0.1
3. LEAKAGE INDUCTANCE: 1 - 3, 1.0 V @ 100kHz  
SHORT 4 - 6 < 0.7 uHy
4. INTERWINDING CAPACITANCE: with Shield  
Grounded  
1 - 3 to 4 - 6 @ 100 KHz, 1.0V < 2.0 pf
5. TURNS AND PHASE:  
1 - 3 : 4 - 6 = 1 : 1.22 +/- 2%
- 6 DIELECTRIC STRENGTH:  
1500 VAC 1 sec

Note: Designed to operate with Crystal Semiconductor  
CS8401.8402, 8411 & 8412



A	REV.	DATE	ECN	BY	DESCRIPTION	
					Newava Tech. Transformer Watertown, SD 57201 605-886-0264 Power, 1:1.22	
TOLERANCES ON						
.XXX	.XX	ANGLE				
+ -	+ -	+ -				
				DATE	SCALE	MODEL
DRAWN: -						DRAWING NO.
CHECKED: -						S22523
APPROVED: -				NEXT ASSY: -		
THIS PRINT MUST NOT BE COPIED IN WHOLE OR IN PART OR USED DETRIMENTALLY TO OUR INTEREST						SHEET 1 OF 1